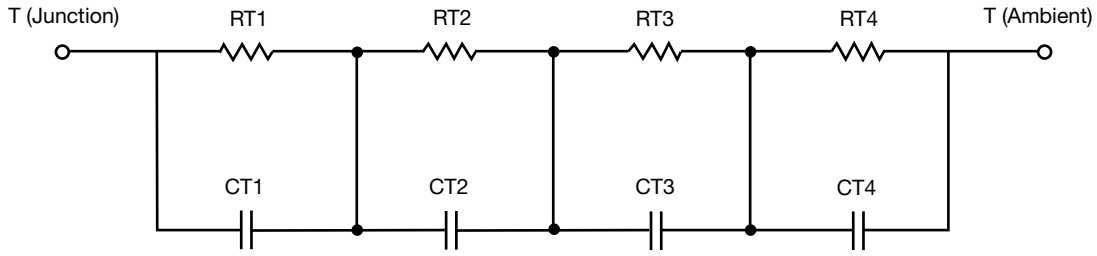
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, “Thermal Simulation of Power MOSFETs on the P-SPICE Platform”.

R-C THERMAL MODEL FOR TANK CONFIGURATION



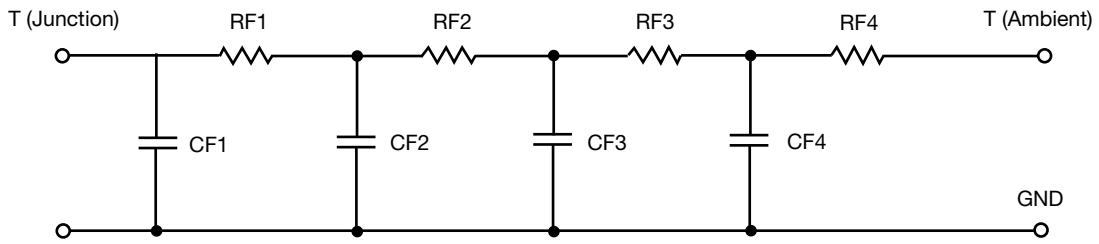
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RT1	n/a	46.1657m	n/a
RT2	n/a	79.3411m	n/a
RT3	n/a	58.9292m	n/a
RT4	n/a	115.5640m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CT1	n/a	995.3079m	n/a
CT2	n/a	573.2441m	n/a
CT3	n/a	93.9680m	n/a
CT4	n/a	5.2389m	n/a

Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RF1	n/a	133.3755m	n/a
RF2	n/a	72.7442m	n/a
RF3	n/a	61.3480m	n/a
RF4	n/a	32.5323m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CF1	n/a	4.9561m	n/a
CF2	n/a	88.2375m	n/a
CF3	n/a	344.7316m	n/a
CF4	n/a	122.0071m	n/a

Note

- n/a indicates not applicable